## **CLAIMS**

We claim:

1. A die, comprising:

a substrate; and

one or more pillar structures formed over the substrate in a pattern.

- 2. The die of claim 1, wherein the one or more pillar structures have a rectangular shape, a round shape, a ring shape, a wall-like shape or a spline shape.
- 3. The die of claim 1, wherein the one or more pillar structures have a rectangular shape with a length of from about 789.0 to 1289.0  $\mu$ m and a width of about 289.0  $\mu$ m.
- 4. The die of claim 1, wherein the one or more pillar structures have a rectangular shape with a length of about 789.0  $\mu m$  and a width of about 289.0  $\mu m$ .
- 5. The die of claim 1, wherein the one or more pillar structures have a rectangular shape with a length of about 1289.0  $\mu m$  and a width of about 289.0  $\mu m$ .
- 6. The die of claim 1, wherein the one or more pillar structures have a rectangular shape and the pillar structures are spaced apart lengthwise by about 500.0  $\mu m$  center-to-center and by about 211.0  $\mu m$  end-to-end.

- 7. The die of claim 1, wherein the one or more pillar structures have a round shape with a diameter of about 289.0  $\mu m$ .
- 8. The die of claim 1, wherein the one or more pillar structures have a round shape with a diameter of about 289.0  $\mu$ m; the pillar structures being arranged at least in part in rows and columns with the adjacent round pillar structures being spaced apart by about 500.0  $\mu$ m.
- 9. The die of claim 1, wherein the pillar structure pattern includes a series of rows and columns.
- 10. The die of claim 1, wherein the pillar structure pattern 100 includes a series of rows and columns; the pillar structures arranged in the series of rows and columns are spaced apart lengthwise by about 500.0  $\mu$ m center-to-center in the columns and are spaced apart about 211.0  $\mu$ m end-to-end.
- 11. The die of claim 1, wherein the one or more pillar structures include at least one wall-shaped pillar structure.
- 12. The die of claim 1, wherein the one or more pillar structures include at least one wall-shaped pillar structure forming a square.
- 13. The die of claim 1, including a pillar wall.
- 14. The die of claim 1, wherein the one or more pillar structures are comprised of a lead-free material.

- 15. The die of claim 1, wherein the one or more pillar structures are comprised of copper.
- 16. The die of claim 1, wherein the one or more pillar structures are comprised of copper coated with oxide, chromium or nickel.
- 17. The die of claim 1, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying solder layer.
- 18. The die of claim 1, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying reflowed solder layer.
- 19. The die of claim 1, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying solder layer; the solder layer being comprised of:

from about 60 to 70% tin and from about 30 to 40% lead; about 63% tin and 37% lead; about 99% tin and SnAg; or 100% tin.

20. The die of claim 1, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying solder layer; the solder layer being comprised of:

about 63% tin and 37% lead; or 100% tin.

- 21. The die of claim 1, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying reflowed solder layer; the pillar structures having a total height of from about 60 to 150  $\mu m$ .
- 22. The die of claim 1, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying reflowed solder layer; the pillar structures having a total height of about  $100~\mu m$ .
- 23. The die of claim 1, wherein the die is used in Surface Acoustic Wave devices and in MEM devices.

## 24. A die, comprising:

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a substrate; and

one or more pillar structures formed over the substrate in a pattern; the one or more pillar structures having a rectangular shape, a round shape, a ring shape, a wall-like shape or a spline shape.

- 25. The die of claim 24, wherein the one or more pillar structures have a rectangular shape with a length of from about 789.0 to 1289.0  $\mu$ m and a width of about 289.0  $\mu$ m.
- 26. The die of claim 24, wherein the one or more pillar structures have a rectangular shape with a length of about 789.0  $\mu$ m and a width of about 289.0  $\mu$ m.

- 27. The die of claim 24, wherein the one or more pillar structures have a rectangular shape with a length of about 1289.0  $\mu$ m and a width of about 289.0  $\mu$ m.
- 28. The die of claim 24, wherein the one or more pillar structures have a rectangular shape and the pillar structures are spaced apart lengthwise by about  $500.0 \, \mu m$  center-to-center and by about  $211.0 \, \mu m$  end-to-end.
- 29. The die of claim 24, wherein the one or more pillar structures have a round shape with a diameter of about 289.0  $\mu$ m.
- 30. The die of claim 24, wherein the one or more pillar structures have a round shape with a diameter of about 289.0  $\mu$ m; the pillar structures being arranged at least in part in rows and columns with the adjacent round pillar structures being spaced apart by about 500.0  $\mu$ m.
- 31. The die of claim 24, wherein the pillar structure pattern includes a series of rows and columns.
- 32. The die of claim 24, wherein the pillar structure pattern 100 includes a series of rows and columns; the pillar structures arranged in the series of rows and columns are spaced apart lengthwise by about 500.0  $\mu$ m center-to-center in the columns and are spaced apart about 211.0  $\mu$ m end-to-end.
- 33. The die of claim 24, wherein the one or more pillar structures include at least one wall-shaped pillar structure.

- 34. The die of claim 24, wherein the one or more pillar structures include at least one wall-shaped pillar structure forming a square.
- 35. The die of claim 24, including a pillar wall.
- 36. The die of claim 24, wherein the one or more pillar structures are comprised of a lead-free material.
- 37. The die of claim 24, wherein the one or more pillar structures are comprised of copper.
- 38. The die of claim 24, wherein the one or more pillar structures are comprised of copper coated with oxide, chromium or nickel.
- 39. The die of claim 24, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying solder layer.
- 40. The die of claim 24, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying reflowed solder layer.
- 41. The die of claim 24, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying solder layer; the solder layer being comprised of:

from about 60 to 70% tin and from about 30 to 40% lead; about 63% tin and 37% lead; about 99% tin and SnAg; or

100% tin.

42. The die of claim 24, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying solder layer; the solder layer being comprised of:

about 63% tin and 37% lead; or 100% tin.

- 43. The die of claim 24, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying reflowed solder layer; the pillar structures having a total height of from about 60 to 150  $\mu m$ .
- 44. The die of claim 24, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying reflowed solder layer; the pillar structures having a total height of about  $100 \, \mu m$ .
- 45. The die of claim 24, wherein the die is used in Surface Acoustic Wave devices and in MEM devices.
- 46. A method of forming a die, comprising the steps:

providing a substrate; and

forming one or more pillar structures over the substrate in a pattern.

47. The method of claim 46, wherein the one or more pillar structures have a rectangular shape, a round shape, a ring shape, a wall-like shape or a spline shape.

- 48. The method of claim 46, wherein the one or more pillar structures have a rectangular shape with a length of from about 789.0 to 1289.0  $\mu$ m and a width of about 289.0  $\mu$ m.
- 49. The method of claim 46, wherein the one or more pillar structures have a rectangular shape with a length of about 789.0  $\mu$ m and a width of about 289.0  $\mu$ m.
- 50. The method of claim 46, wherein the one or more pillar structures have a rectangular shape with a length of about 1289.0  $\mu$ m and a width of about 289.0  $\mu$ m.
- 51. The method of claim 46, wherein the one or more pillar structures have a rectangular shape and the pillar structures are spaced apart lengthwise by about 500.0  $\mu$ m center-to-center and by about 211.0  $\mu$ m end-to-end.
- 52. The method of claim 46, wherein the one or more pillar structures have a round shape with a diameter of about 289.0  $\mu$ m.
- 53. The method of claim 46, wherein the one or more pillar structures have a round shape with a diameter of about 289.0  $\mu$ m; the pillar structures being arranged at least in part in rows and columns with the adjacent round pillar structures being spaced apart by about 500.0  $\mu$ m.
- 54. The method of claim 46, wherein the pillar structure pattern includes a series of rows and columns.

- 55. The method of claim 46, wherein the pillar structure pattern 100 includes a series of rows and columns; the pillar structures arranged in the series of rows and columns are spaced apart lengthwise by about 500.0  $\mu$ m center-to-center in the columns and are spaced apart about 211.0  $\mu$ m end-to-end.
- 56. The method of claim 46, wherein the one or more pillar structures include at least one wall-shaped pillar structure.
- 57. The method of claim 46, wherein the one or more pillar structures include at least one wall-shaped pillar structure forming a square.
- 58. The method of claim 46, including a pillar wall.
- 59. The method of claim 46, wherein the one or more pillar structures are comprised of a lead-free material.
- 60. The method of claim 46, wherein the one or more pillar structures are comprised of copper.
- 61. The method of claim 46, wherein the one or more pillar structures are comprised of copper coated with oxide, chromium or nickel.
- 62. The method of claim 46, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying solder layer.

- 63. The method of claim 46, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying reflowed solder layer.
- 64. The method of claim 46, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying solder layer; the solder layer being comprised of:

from about 60 to 70% tin and from about 30 to 40% lead; about 63% tin and 37% lead; about 99% tin and SnAg; or 100% tin.

65. The method of claim 46, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying solder layer; the solder layer being comprised of:

about 63% tin and 37% lead; or 100% tin.

- 66. The method of claim 46, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying reflowed solder layer; the pillar structures having a total height of from about 60 to 150  $\mu m$ .
- 67. The method of claim 46, wherein the one or more pillar structures are comprised of a lower copper layer and an overlying reflowed solder layer; the pillar structures having a total height of about  $100 \, \mu m$ .

68. The method of claim 46, wherein the die formed is used in Surface Acoustic Wave devices and in MEM devices.